



**THE DATASHEET OF
74CBTLVD3861DK,118**



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74CBTLVD3861

10-bit level-shifting bus switch with output enable

Rev. 4 — 14 December 2011

Product data sheet

1. General description

The 74CBTLVD3861 is a 10-bit 3.3 V to 1.8 V level translating bus switch with one output enable (\overline{OE}) input. When \overline{OE} is LOW, the switch is closed and port A is connected to the B port. When \overline{OE} is HIGH, the switch is disabled.

To ensure the high-impedance OFF-state during power-up or power-down, \overline{OE} should be tied to the V_{CC} through a pull-up resistor. The minimum value of the resistor is determined by the current-sinking capability of the driver.

Schmitt trigger action at control input makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 3.0 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} .

2. Features and benefits

- Supply voltage range from 3.0 V to 3.6 V
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-B/JESD36 (3.0 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- 4 Ω switch connection between two ports
- 3.3 V to 1.8 V level translation
- CMOS low power consumption
- Latch-up performance exceeds 250 mA per JESD78B Class I level A
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$



3. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|----------------|-------------------|-----------------------|--|----------|
| | Temperature range | Name | Description | |
| 74CBTLVD3861DK | -40 °C to +125 °C | SSOP24 ^[1] | plastic shrink small outline package; 24 leads; body width 3.9 mm; lead pitch 0.635 mm | SOT556-1 |
| 74CBTLVD3861PW | -40 °C to +125 °C | TSSOP24 | plastic thin shrink small outline package; 24 leads; body width 4.4 mm | SOT355-1 |
| 74CBTLVD3861BQ | -40 °C to +125 °C | DHVQFN24 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 × 5.5 × 0.85 mm | SOT815-1 |

[1] Also known as QSOP24 package

4. Functional diagram

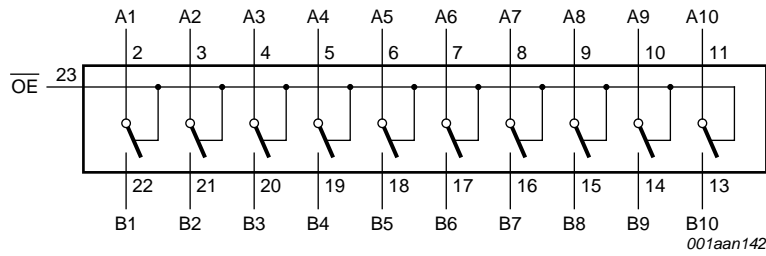


Fig 1. Logic symbol

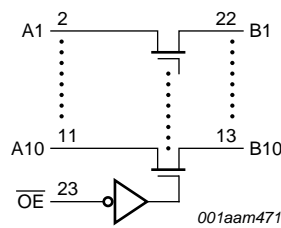


Fig 2. Logic diagram

5. Pinning information

5.1 Pinning

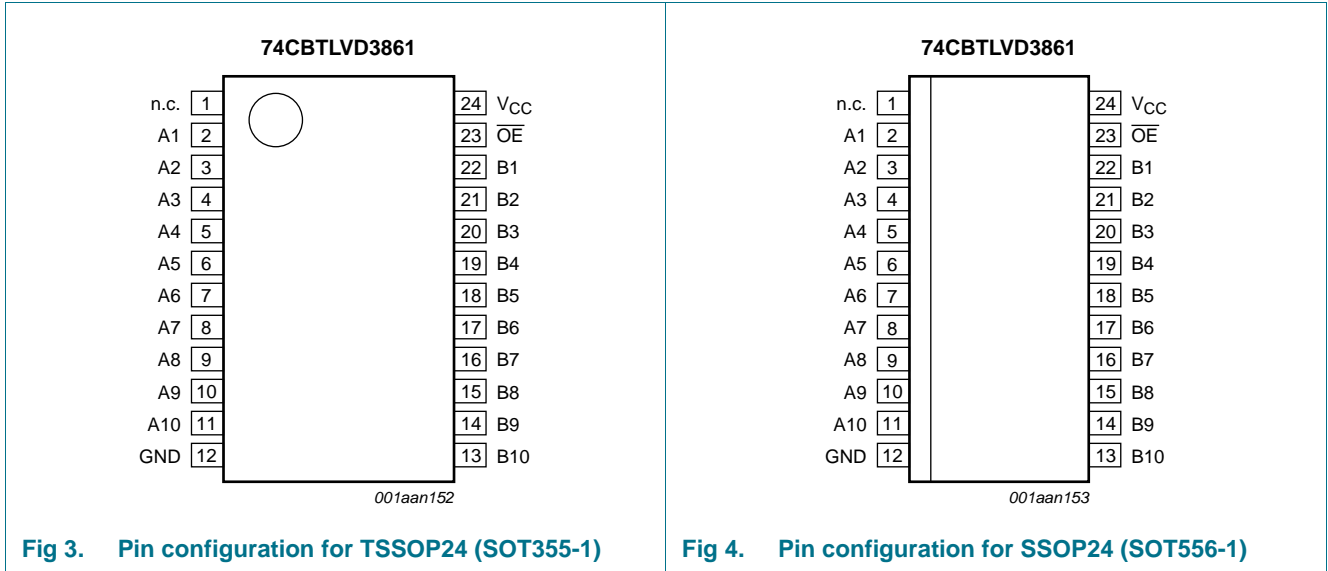
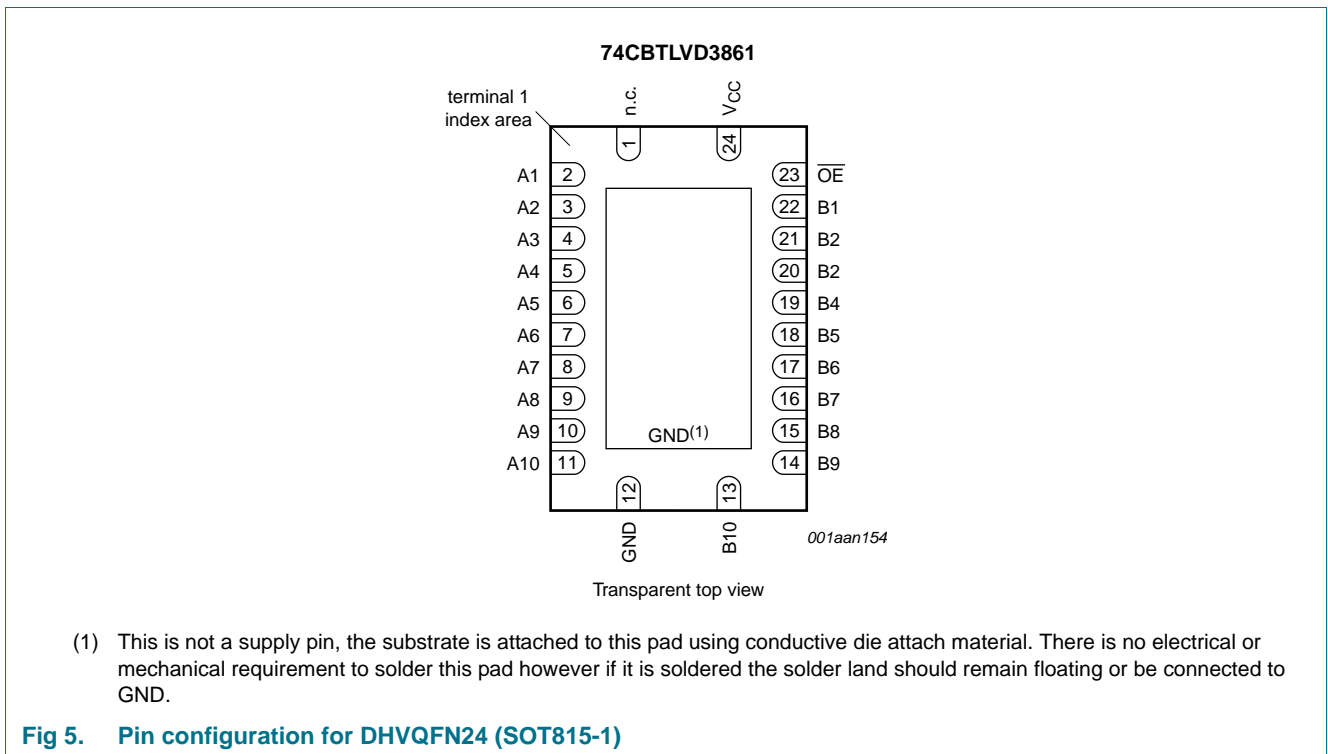


Fig 3. Pin configuration for TSSOP24 (SOT355-1)

Fig 4. Pin configuration for SSOP24 (SOT556-1)



(1) This is not a supply pin, the substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad however if it is soldered the solder land should remain floating or be connected to GND.

Fig 5. Pin configuration for DHVQFN24 (SOT815-1)

5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|--|----------------------------------|
| nc | 1 | not connected |
| A1 to A10 | 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 | data input/output (A port) |
| GND | 12 | ground (0 V) |
| B1 to B10 | 22, 21, 20, 19, 18, 17, 16, 15, 14, 13 | data input/output (B port) |
| \overline{OE} | 23 | output enable input (active LOW) |
| V_{CC} | 24 | positive supply voltage |

6. Functional description

Table 3. Function selection^[1]

| Input | Input/output |
|-----------------|--------------|
| \overline{OE} | An, Bn |
| L | An = Bn |
| H | Z |

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|-------------------------------|---------------------|----------------|------|
| V_{CC} | supply voltage | | -0.5 | +4.6 | V |
| V_I | input voltage | | ^[1] -0.5 | +4.6 | V |
| V_{SW} | switch voltage | enable and disable mode | ^[1] -0.5 | $V_{CC} + 0.5$ | V |
| I_{IK} | input clamping current | $V_I < -0.5$ V | -50 | - | mA |
| I_{SK} | switch clamping current | $V_I < -0.5$ V | -50 | - | mA |
| I_{SW} | switch current | $V_{SW} = 0$ V to V_{CC} | - | ±128 | mA |
| I_{CC} | supply current | | - | +100 | mA |
| I_{GND} | ground current | | -100 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C | ^[2] - | 500 | mW |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SSOP24 and TSSOP24 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.
For DHVQFN24 package: P_{tot} derates linearly at 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-------------------------------------|---|-----|----------|------|
| V_{CC} | supply voltage | | 3.0 | 3.6 | V |
| V_I | input voltage | | 0 | 3.6 | V |
| V_{SW} | switch voltage | enable and disable mode | 0 | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | [1] | 200 | ns/V |

[1] Applies to control signal levels.

9. Static characteristics

Table 6. Static characteristics

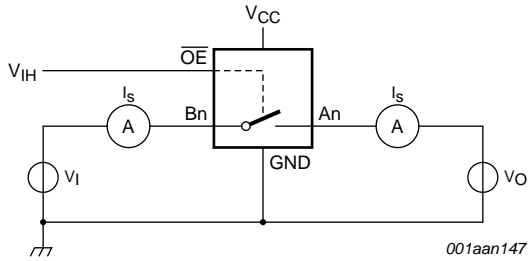
At recommended operating conditions voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | $T_{amb} = -40\text{ °C to }+85\text{ °C}$ | | | $T_{amb} = -40\text{ °C to }+125\text{ °C}$ | | Unit |
|-----------------|---------------------------|---|--|--------------------|----------|---|----------|---------------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | 2.0 | - | - | 2.0 | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ | - | - | 0.9 | - | 0.9 | V |
| I_I | input leakage current | pin \overline{OE} ; $V_I = \text{GND to }V_{CC}$; $V_{CC} = 3.6\text{ V}$ | - | - | ± 1 | - | ± 20 | μA |
| V_{pass} | pass voltage | $V_I = V_{CC}$; see Figure 8 to Figure 12 | - | - | - | - | - | V |
| $I_{S(OFF)}$ | OFF-state leakage current | $V_{CC} = 3.6\text{ V}$; see Figure 6 | - | - | ± 1 | - | ± 20 | μA |
| $I_{S(ON)}$ | ON-state leakage current | $V_{CC} = 3.6\text{ V}$; see Figure 7 | - | - | ± 1 | - | ± 20 | μA |
| I_{OFF} | power-off leakage current | V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V}$ | - | - | ± 10 | - | ± 50 | μA |
| I_{CC} | supply current | $V_I = V_{CC}$; $I_O = 0\text{ A}$; $V_{CC} = 3.6\text{ V}$; $V_{SW} = \text{GND or }V_{CC}$ | - | - | 20 | - | 50 | μA |
| | | $V_I = \text{GND}$; $I_O = 0\text{ A}$; $V_{CC} = 3.6\text{ V}$; $V_{SW} = \text{GND or }V_{CC}$ | - | - | 100 | - | 150 | μA |
| ΔI_{CC} | additional supply current | pin \overline{OE} ; $V_I = V_{CC} - 0.6\text{ V}$; $V_{SW} = \text{GND or }V_{CC}$; $V_{CC} = 3.6\text{ V}$ | [2] | - | 300 | - | 2000 | μA |
| C_I | input capacitance | pin \overline{OE} ; $V_{CC} = 3.3\text{ V}$; $V_I = 0\text{ V to }3.3\text{ V}$ | - | 0.9 | - | - | - | pF |
| $C_{S(OFF)}$ | OFF-state capacitance | $V_{CC} = 3.3\text{ V}$; $V_I = 0\text{ V to }3.3\text{ V}$ | - | 2.5 | - | - | - | pF |
| $C_{S(ON)}$ | ON-state capacitance | $V_{CC} = 3.3\text{ V}$; $V_I = 0\text{ V to }3.3\text{ V}$ | - | 9.0 | - | - | - | pF |

[1] All typical values are measured at $T_{amb} = 25\text{ °C}$.

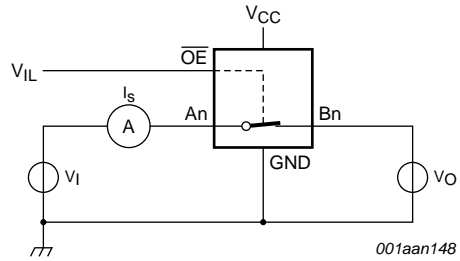
[2] One input at 3 V, other inputs at V_{CC} or GND.

9.1 Test circuits



$V_I = V_{CC}$ or GND and $V_O = GND$ or V_{CC} .

Fig 6. Test circuit for measuring OFF-state leakage current (one switch)



$V_I = V_{CC}$ or GND and $V_O =$ open circuit.

Fig 7. Test circuit for measuring ON-state leakage current (one switch)

9.2 Typical pass voltage graphs

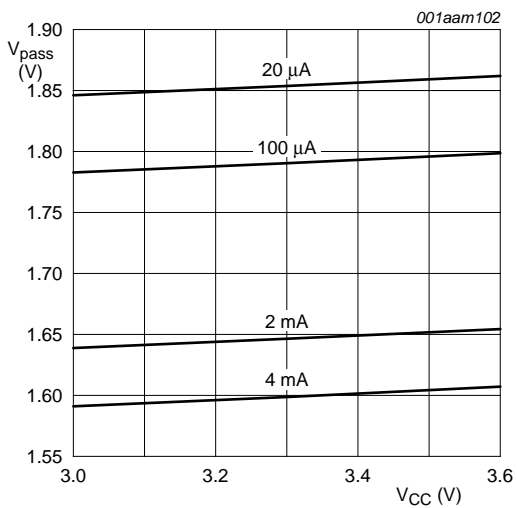


Fig 8. Pass voltage versus supply voltage; $T_{amb} = 125\text{ }^\circ\text{C}$ (typical)

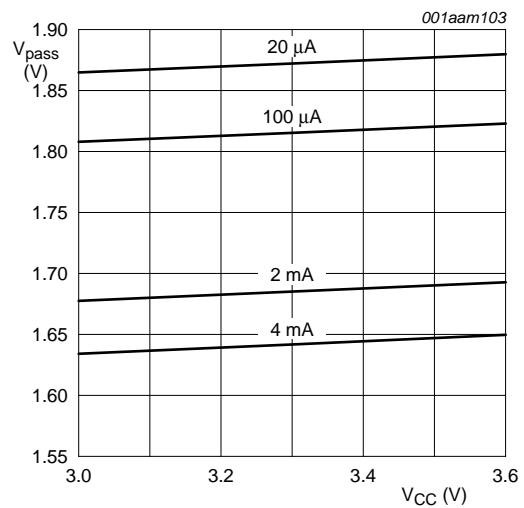


Fig 9. Pass voltage versus supply voltage; $T_{amb} = 85\text{ }^\circ\text{C}$ (typical)

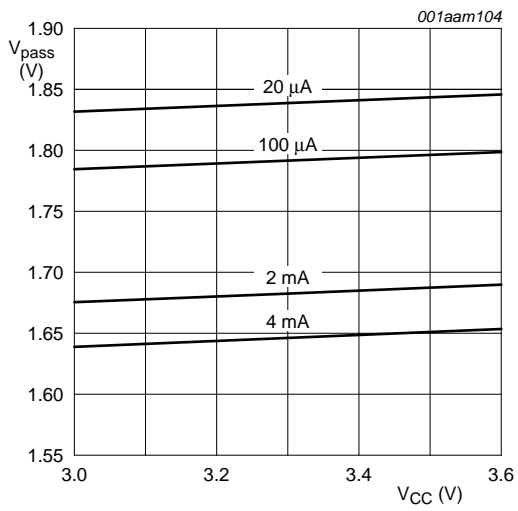


Fig 10. Pass voltage versus supply voltage; T_{amb} = 25 °C (typical)

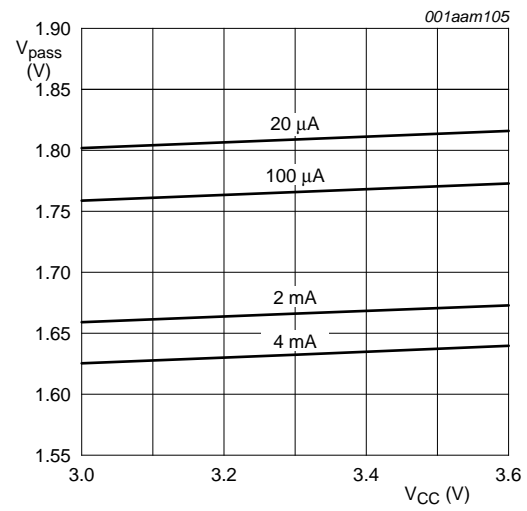


Fig 11. Pass voltage versus supply voltage; T_{amb} = 0 °C (typical)

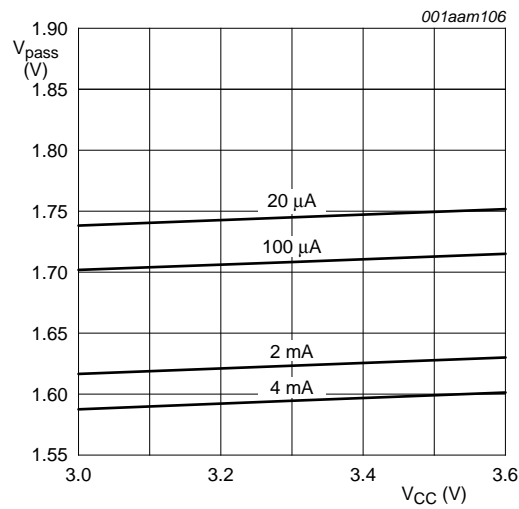


Fig 12. Pass voltage versus supply voltage; T_{amb} = -40 °C (typical)

9.3 ON resistance

Table 7. Resistance R_{ON}

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

| Symbol | Parameter | Conditions | $T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$ | | | $T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$ | | Unit |
|----------|---------------|--|--|--------------------|------|---|------|----------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| R_{ON} | ON resistance | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$ ^[2] | | | | | | |
| | | $I_{SW} = 64\text{ mA}; V_I = 0\text{ V}$ | - | 3.7 | 7.0 | - | 10.0 | Ω |
| | | $I_{SW} = 24\text{ mA}; V_I = 0\text{ V}$ | - | 3.7 | 7.0 | - | 10.0 | Ω |
| | | $I_{SW} = 15\text{ mA}; V_I = 1.2\text{ V}$ | - | 4.7 | 10.0 | - | 12.0 | Ω |

- [1] Typical values are measured at $T_{amb} = 25\text{ }^{\circ}\text{C}$ and nominal V_{CC} .
- [2] Measured by the voltage drop between the An and Bn terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (An or Bn) terminals.

9.4 ON resistance test circuit

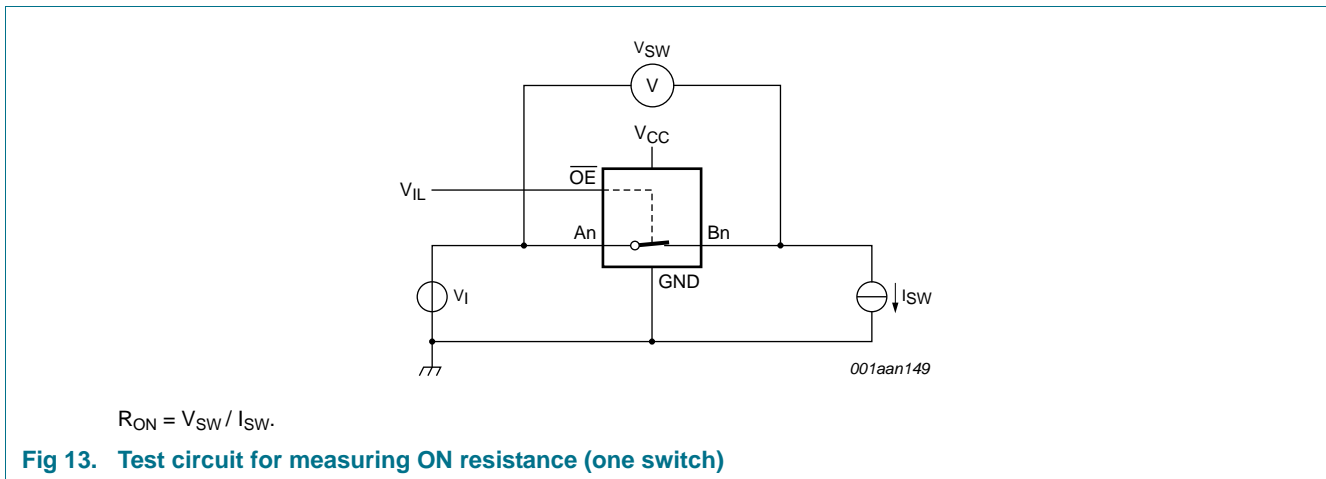


Fig 13. Test circuit for measuring ON resistance (one switch)

10. Dynamic characteristics

Table 8. Dynamic characteristics
GND = 0 V; for test circuit see Figure 16

| Symbol | Parameter | Conditions | T _{amb} = -40 °C to +85 °C | | | T _{amb} = -40 °C to +125 °C | | Unit |
|------------------|-------------------|-------------------------------------|-------------------------------------|--------------------|------|--------------------------------------|------|------|
| | | | Min | Typ ^[1] | Max | Min | Max | |
| t _{pd} | propagation delay | An to Bn or Bn to An; see Figure 14 | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.11 | - | 0.22 | ns |
| t _{en} | enable time | OE to An or Bn; see Figure 15 | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 1.5 | 2.9 | 5.0 | 1.5 | 6.0 | ns |
| t _{dis} | disable time | OE to An or Bn; see Figure 15 | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 0.8 | 3.3 | 7.0 | 0.8 | 8.0 | ns |

- [1] All typical values are measured at T_{amb} = 25 °C and at nominal V_{CC}.
- [2] The propagation delay is the calculated RC time constant of the on-state resistance of the switch and the load capacitance, when driven by an ideal voltage source (zero output impedance).
- [3] t_{pd} is the same as t_{PLH} and t_{PHL}.
- [4] t_{en} is the same as t_{PZH} and t_{PZL}.
- [5] t_{dis} is the same as t_{PHZ} and t_{PLZ}.

10.1 Waveforms

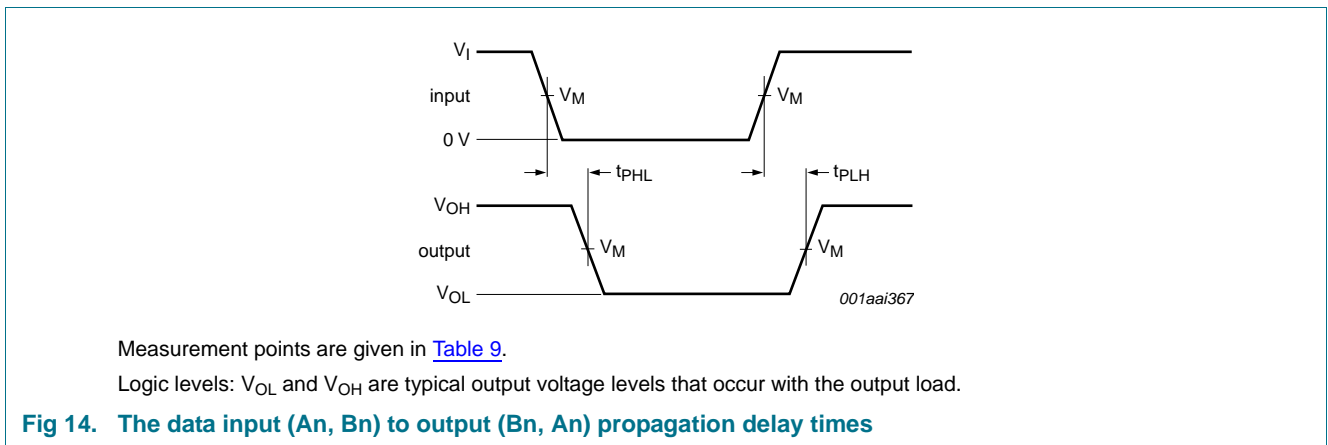
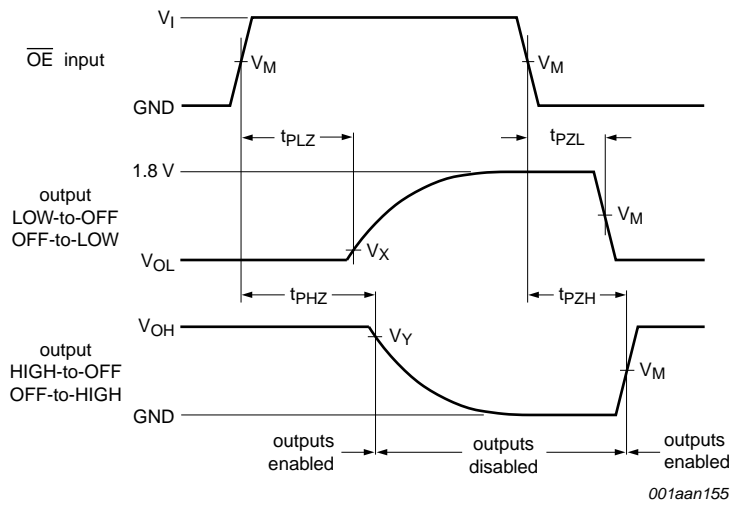


Table 9. Measurement points

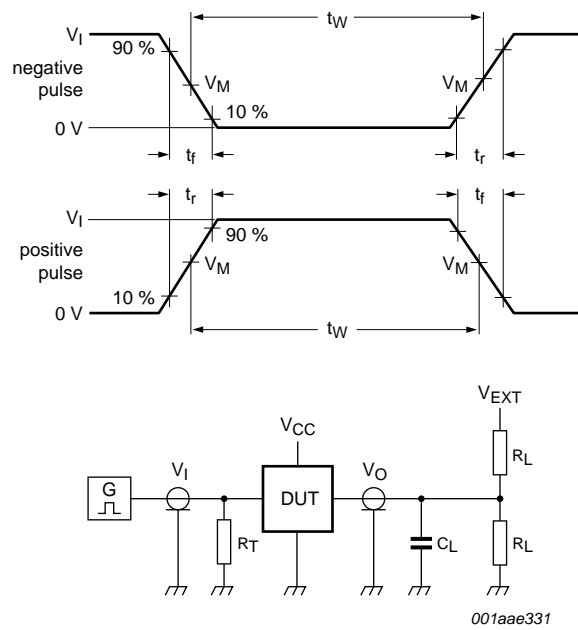
| Supply voltage | Input | | | Output | | |
|-----------------|--------------------|-----------------|---------------------------------|----------------|--------------------------|--------------------------|
| V _{CC} | V _M | V _I | t _r = t _f | V _M | V _X | V _Y |
| 3.0 V to 3.6 V | 0.5V _{CC} | V _{CC} | ≤ 2.0 ns | 0.9 V | V _{OL} + 0.15 V | V _{OH} - 0.15 V |



Measurement points are given in [Table 9](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 15. Enable and disable times



Test data is given in [Table 10](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 16. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Load | | V_{EXT} | | |
|----------------|-------|-------|--------------------|--------------------|--------------------|
| V_{CC} | C_L | R_L | t_{PLH}, t_{PHL} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 3.0 V to 3.6 V | 30 pF | 1 kΩ | open | GND | 3.6 V |

10.2 Additional dynamic characteristics

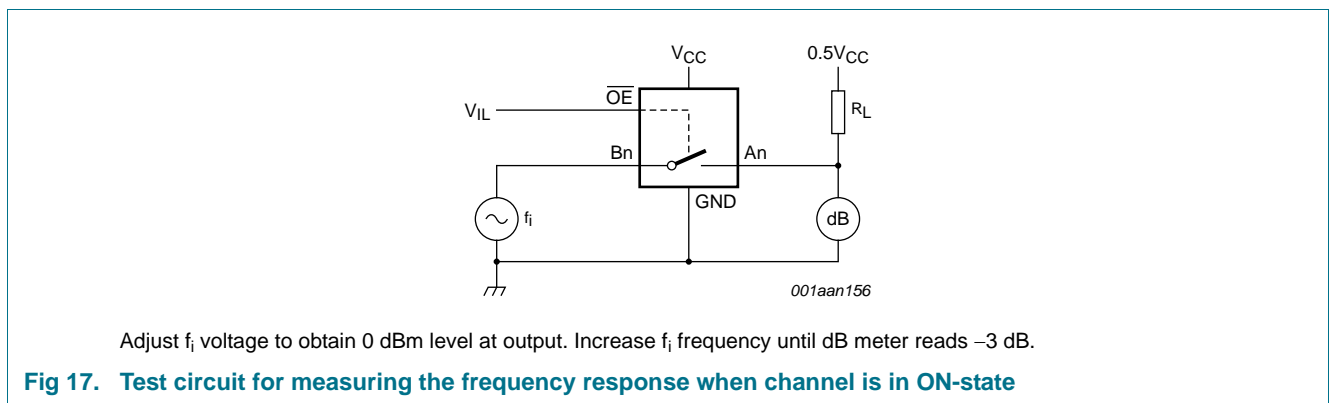
Table 11. Additional dynamic characteristics

GND = 0 V.

| Symbol | Parameter | Conditions | T _{amb} = 25 °C | | | Unit | |
|---------------------|--------------------------|---|--------------------------|-----|-----|------|-----|
| | | | Min | Typ | Max | | |
| f _(-3dB) | -3 dB frequency response | V _{CC} = 3.3 V; R _L = 50 Ω; see Figure 17 | [1] | - | 575 | - | MHz |

[1] f_i is biased at 0.5V_{CC}.

10.3 Test circuit



11. Package outline

SSOP24: plastic shrink small outline package; 24 leads; body width 3.9 mm; lead pitch 0.635 mm SOT556-1

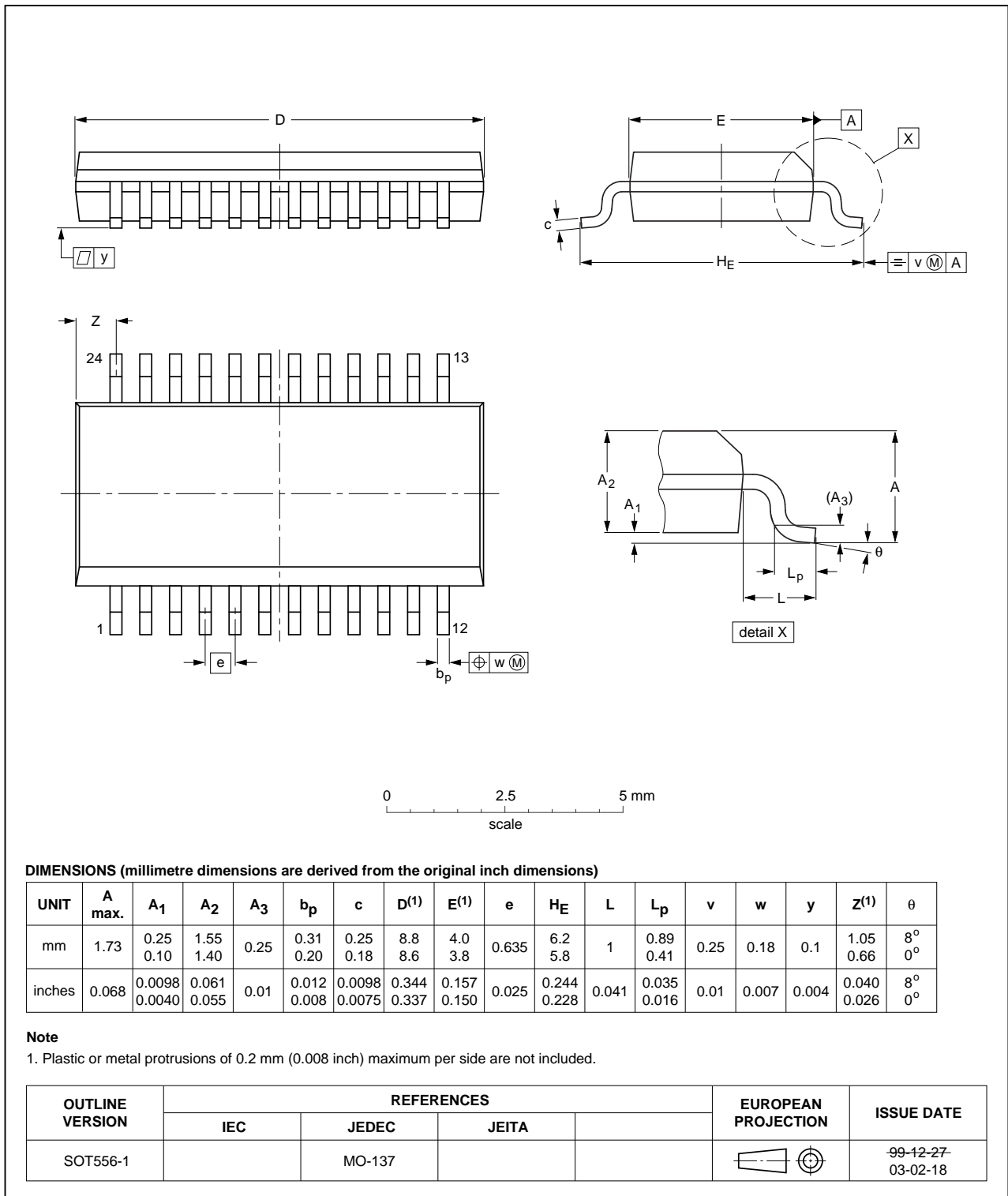


Fig 18. Package outline SOT556-1 (SSOP24)

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1

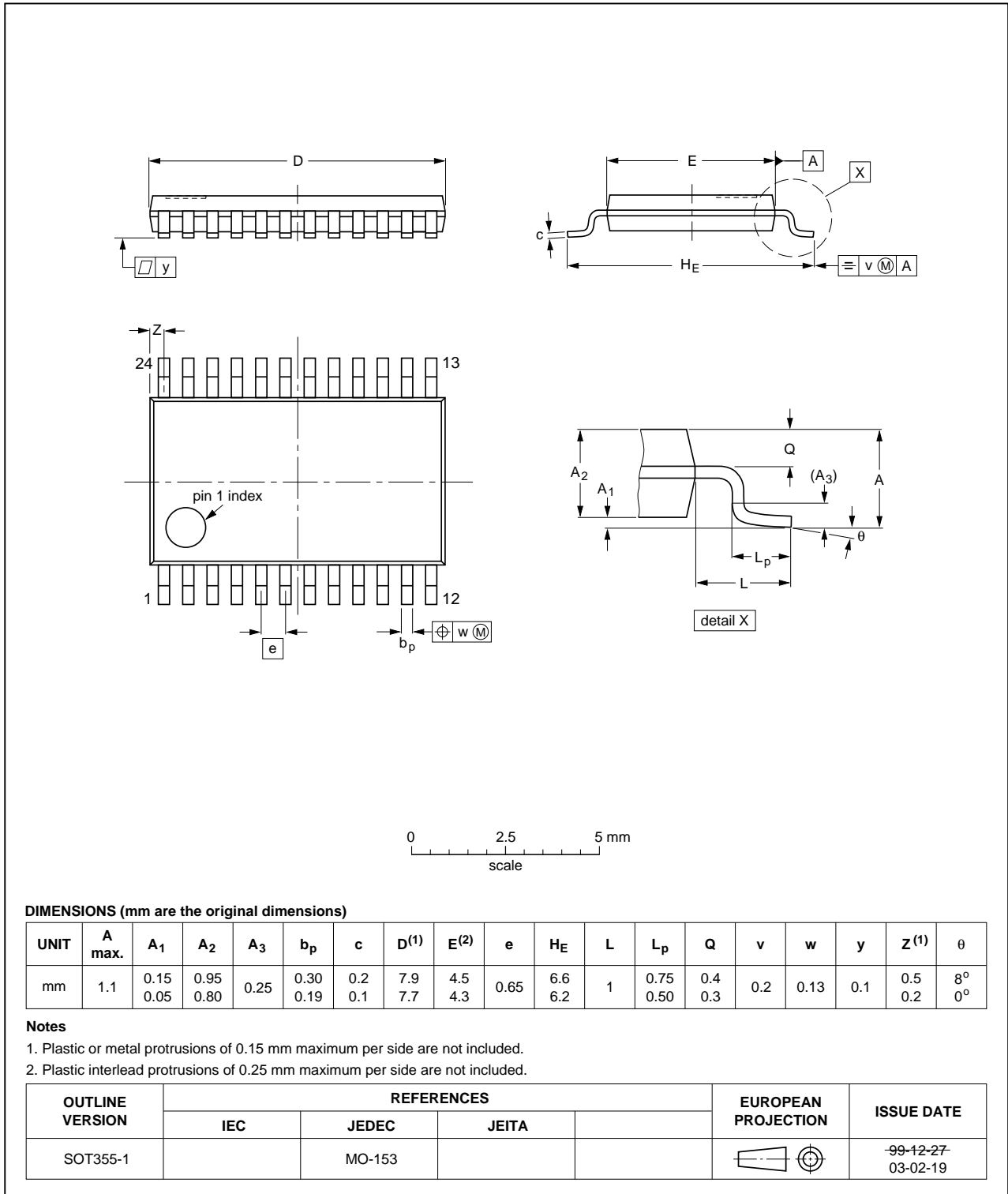


Fig 19. Package outline SOT355-1 (TSSOP24)

DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 x 5.5 x 0.85 mm

SOT815-1

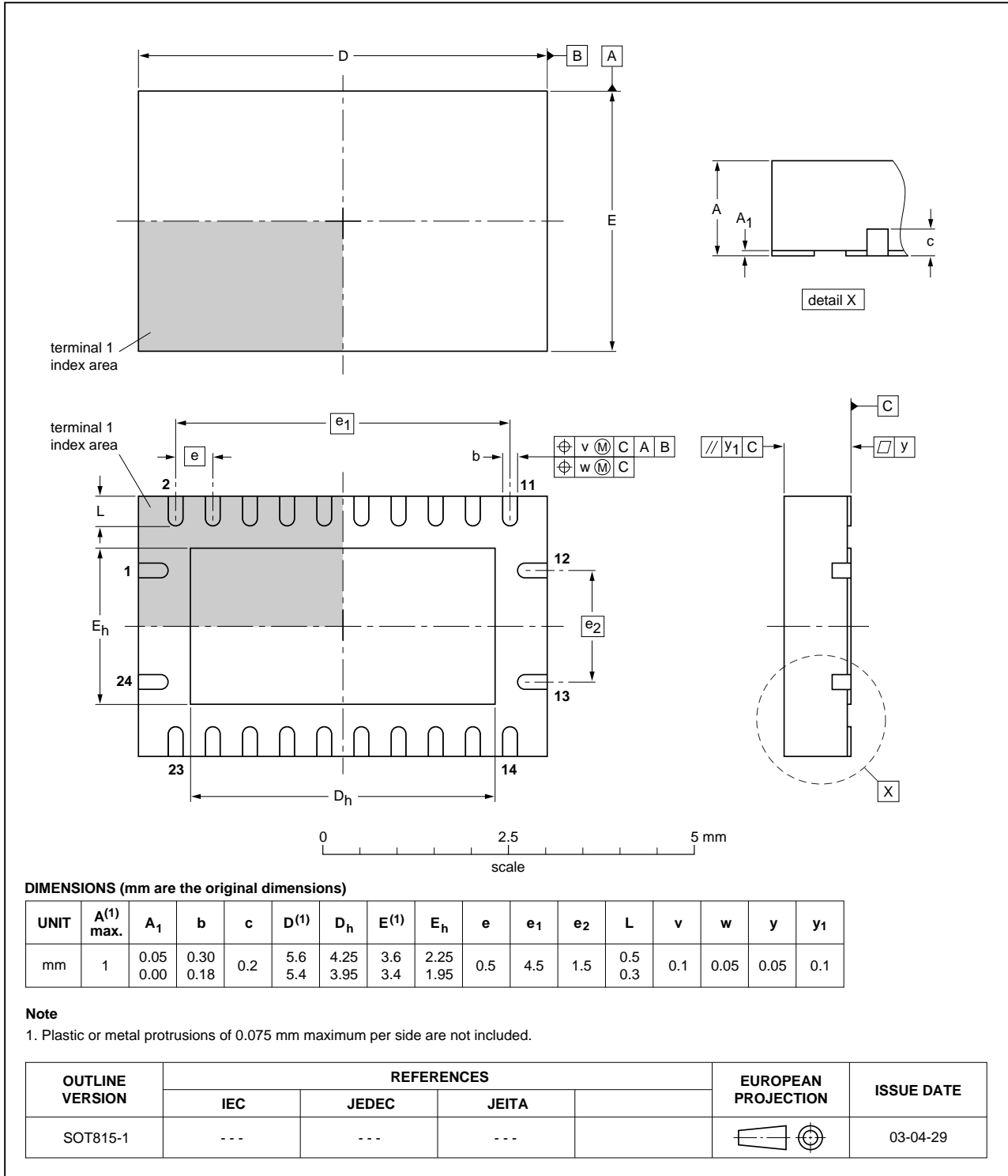


Fig 20. Package outline SOT815-1 (DHVQFN24)

12. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|---|
| CDM | Charged Device Model |
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |

13. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|------------------|--|--------------------|---------------|------------------|
| 74CBTLVD3861 v.4 | 20111214 | Product data sheet | - | 74CBTLVD3861 v.3 |
| Modifications: | <ul style="list-style-type: none">Legal pages updated. | | | |
| 74CBTLVD3861 v.3 | 20111020 | Product data sheet | - | 74CBTLVD3861 v.2 |
| 74CBTLVD3861 v.2 | 20110117 | Product data sheet | - | 74CBTLVD3861 v.1 |
| 74CBTLVD3861 v.1 | 20101206 | Product data sheet | - | - |

14. Legal information

14.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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16. Contents

1 General description 1

2 Features and benefits 1

3 Ordering information 2

4 Functional diagram 2

5 Pinning information 3

5.1 Pinning 3

5.2 Pin description 4

6 Functional description 4

7 Limiting values 4

8 Recommended operating conditions 5

9 Static characteristics 5

9.1 Test circuits 6

9.2 Typical pass voltage graphs 6

9.3 ON resistance 8

9.4 ON resistance test circuit 8

10 Dynamic characteristics 9

10.1 Waveforms 9

10.2 Additional dynamic characteristics 12

10.3 Test circuit 12

11 Package outline 13

12 Abbreviations 16

13 Revision history 16

14 Legal information 17

14.1 Data sheet status 17

14.2 Definitions 17

14.3 Disclaimers 17

14.4 Trademarks 18

15 Contact information 18

16 Contents 19

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